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Molecularly Engineered Thienyl-Triphenylamine Substituted Zinc Phthalocyanine as Dopant Free Hole Transporting Materials in Perovskite Solar Cells

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To endure the success of perovskite solar cells (PSCs), developing dopant-free hole transporting materials is of paramount importance to induce long-term stability. Phthalocyanine has emerged as a viable alternative for common Spiro-OMeTAD, due to their excellent optoelectrical properties and chemical stability. We report the design and semiconducting properties of a thienyl-triphenylamine tetrasubstituted Zinc (II) phthalocyanine, and its application into PSCs. The PSCs fabricated with Zinc phthalocyanine without the use of any dopant and additives gave a competitive power conversion efficiency of over 14%, along with long-term stability.

Introduction

The last decade has witnessed an enormous development in the investigation of organic-inorganic hybrid perovskite solar cells (PSCs) due to their power conversion efficiency (PCE) skyrocketing from 3.8% to 25.2%.^{1–5} This rapid development is due to the outstanding properties of organic-inorganic halide perovskites: panchromatic light absorption and long-range ambipolar carrier diffusion as well as the choice of solutionprocessability at low temperature.^{6–8} In the device configuration of PSCs, the light harvester perovskites layers are sandwiched between an electron and hole transporting material (ETM, HTM). This can be sub-divided into normal (n-ip) and inverted (p-i-n) structures according to whether ETM or HTM is in contact with the bottom transparent conductive electrode (TCO).

In a standard normal device structure (TCO/ETM/perovskite/HTM/metal electrode), HTMs atop of perovskite layer play pivotal roles in achieving high efficiency and long-term stability in PSCs. The hole transporting layers extract and transport photo-generated holes from perovskite to the metal electrode rapidly, avoiding undesired charge recombination losses at the interfaces and also inhibits the degradation process induced by oxygen and moisture.^{9–11} An effective HTM must fulfill the following requirements: simplified

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synthesis procedure, solution-processability, uniform film formation (compact morphology) without any pinhole, the relatively high charge transporting abilities, the well aligned highest occupied molecular orbital (HOMO))/valence band with valence band of perovskite, superior stability under ambient and thermal condition.^{12–15}

То date. 2,2',7,7'-tetrakis-(N,N-di-pmethoxyphenylamine)-9,9'-spirobifluorene (Spiro-OMeTAD) is most investigated HTM in n-i-p structure devices because of their simple orthogonal solution-processability (to common perovskites) and high performance of the devices.^{16–21} However, Spiro-OMeTAD possesses low conductivity and mobility in its pristine form, and introducing a hygroscopic *p*-type dopant and additive such as lithium bis(trifluoromethanesulfonyl)imide (Li-TFSI) and 4-tert-Butylpyridine (tBP) is prerequisite to enhance the charge transporting ability of Spiro-OMeTAD, but on the other hand, this can also accelerate the degradation of perovskite and lowers the stability of the devices. The tedious multi-step synthesis and costly purification process of this HTM along with the use of indispensable hydrophilic dopants and additives limits its further extensive application in PSCs.^{22,23} Recently, the other alternatives that meet HTM'scriteria, including small molecules, conjugated polymers, and inorganic p-type semiconductors , etc., have been specially designed and synthesized to supersede Spiro-

OMeTAD.^{12,14,15,24–26} Among them, one such promising category of novel HTM is metal phthalocyanine analogs (Pcs), which own organic macrocycles with an extended π -conjugated system andplanar structure.^{27–30} They are cost-effective and very attractive due to their facile synthesis and purification, high hydrophobicity, as well as excellent stability under thermal and photo conditions. Moreover, they exhibit a unique combination of chemical, optical and electronic properties,



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Fig.1 Chemical structure of ZnTPPc.

which can be tailored by the molecular engineering. The peripheral and non-peripheral substitution of Pcs is an effective approach to regulate their chemical and electrical properties. 29,31,32 The efficiency of Pcs-based PSC was significantly improved to over 20% to date since the first paper reported on vacuum-deposited CuPc in PSCs in 2015.^{33–35} Catchpole et al. applied solution-processed copper (II) 2,9,16,23-tetra-tert-butyl-29H,31H-phthalocyanine as a doped HTM for PSCs and reported the highest efficiency of the device with Pcs.³⁵ Recently, Pc derivatives have emerged as an appealing dopant-free HTMs.^{27,36–39} For instance, recently we have introduced dopant-free Zinc (11) 2,9,16,23-tetra-tert-butyl-29H,31Hphthalocyanine dimers with 3,6-bisthienylldiketopyrrolopyrrole (ZnPc-DPP-ZnPc) as dopant-free HTM into PSCs which yielded 16.8% efficiency.⁴⁰ Similarly, Wang et al. successfully developed tetramethoxy ltriphenylamine substituted zinc phthalocyanine (OTPA-ZnPc) as a dopant-free HTM, and corresponding device owned 16.23% NMR and ¹³C-NMR spectroscopy (Fig. S1-S6 in the SI). efficiency as well as improved stability.⁴¹ Xu et al. investigated properties and application of two CuPcs: methoxydiphenylamine / methoxy triphenyl amine-substituted copper Pcs, named as OMe-DPA-CuPc and OMe-TPA-CuPc, respectively. It showed that OMe-TPA-CuPc exhibit better π - π interaction and more parallel orientations of Pc cores in bulk aggregates compared to OMe-DPA-CuPc, and the corresponding dopant-free HTM based PSCs gave higher efficiency (19.7%).³⁷ Substitution with methoxy triphenylamine moieties highlights the strong potential to future design Pc derivatives as dopant-free HTM. Thiophenes or its derivatives as the π -linker are widely investigated as organic semiconducting materials in thin-film devices.^{42,43} Particularly, thienyl groups are employed to synthesize dopant-free small molecules HTMs,43-45 but reports dealing with phthalocyanines analogs with thiophene or its derivatives are in scarce.^{29,46,47}

In this work, guided by rational design, we synthesize and characterize 2,9,16,23-tetra-thienyl-Zinc (11) methoxytriphenylamine-29H,31H-phthalocyanine, named as ZnTPPc (Fig. 1), and its integration as a dopant-free HTM in PSCs is investigated. Notably, the PSC based on dopant-free ZnTPPc delivered a PCE of 14.5%, which is comparable to that of the device employing the well-known doped Spiro-OMeTAD.



Particularly, the facile synthesis of **ZnTPPc** based on commercial precursor materials makes it a promising new class of HTMs with high stability.

Results and discussion

Synthesis and characterization of ZnTPPc

Our objective was to synthesize a tetrasubstituted ZnTPPc with triphenylamine-thienyl conjugated aromatic electron-rich substituents. These substituents were selected in order to improve the solubility and hole mobility of Pc as a HTM. ZnTPPc was synthesized from autocondensation of phthalonitrile 2 in the presence of $Zn(OAc)_2$ and a drop of DBN as catalyst with 52% of yield (Scheme 1). The phthalonitrile 2 was obtained by Suzuki coupling of arylboronate and bromo-thienyl-phthalonitrile 3, which in turn can be easily prepared from 4-(thiophen-2yl)phthalonitrile 4 by bromination with NBS. Phthalonitrile 4 was synthesized by a Suzuki reaction of 4-iodophthalonitrile and thiophene-2-boronic acid pinacol ester. Palladium acetate was the best catalyst for this reaction, better than the usual Pd₂(dba)₃. The phthalonitriles **2-4** were characterized by ¹H-

The final product **ZnTPPc** was systematically characterized by ¹H-NMR spectroscopy, HR-MALDI-TOF mass spectrometry UV-vis absorption and fluorescence spectra. The ¹H-NMR spectra in DMSO- d_6 of **ZnTPPc** showed broad aromatic signals meanwhile the aliphatic ones are well defined. This may be due to aggregation by stacking and to the presence of four different region isomers (Fig. S7 in the SI). The absorption spectra of ZnTPPc in DMF (Fig. 2a) presented the Soret bands located in the ultraviolet region around 390 nm and the Q band in the region between 600 nm and 780 nm. Intensive absorptions at 647 nm and 719 nm, respectively, could be ascribed to strong $\pi-\pi^*$ transitions of Q-band.³⁷ The ZnTPPc show strong, narrow steady-state fluorescence with peak position at 768 nm (Fig. 2a). The optical bandgap (*E*_g) of **ZnTPPc** was estimated from the corresponding intersection of absorption and fluorescence spectra, thus, resulting in 1.65 eV.



Fig.2 (a) UV-vis absorption and fluorescence spectra of **ZnTPPc** in DMF. (b) cyclic voltammogram (100 mV s⁻¹) of deaerated DMF solution of **ZnTPPc** containing TBAPF₆ (0.1 M) at 298K. The inset shows a zoomed view of oxidation peaks. (c) *I*-*V* curves from conductivity measurements (device structure: FTO/HTM/Ag) and (d) *J*-*V* curves of the **ZnTPPc** based hole-only device with structure: FTO/PEDOT:PSS/HTM /Ag. Spiro-OMETAD is referred to as Spiro.

The electrochemical characterization was performed to evaluate the energy level alignment of the perovskite/ZnTPPc interface via using cyclic voltammetry as displayed in Fig. 2b. The ferrocene redox couple was used as the external standard and ZnTPPc showed two oxidation peaks at 0.35 V and 0.79 V (vs Fc/Fc⁺), respectively. The highest occupied molecular orbital energy level (E_{HOMO}) of ZnTPPc was calculated according to Equation: E_{HOMO} =-4.8- E_{ox} , where E_{ox} is the first onset oxidation potential. The E_{HOMO} value was estimated to be -5.15 eV and located in between valence band of perovskite (-5.9 eV) and work function of gold (-5.1 eV), which could facilitate the hole carrier extraction from from perovskite to metal electrode.48 While the lowest unoccupied molecular orbital energy level (ELUMO) of ZnTPPc was -3.44 eV, determined by adding the previously obtained E_{g} to E_{HOMO} value. E_{LUMO} lies higher than the conduction band of perovskite (-4.4 eV), which can efficiently block the photo-generated electron and avoid recombination at the interface of perovskite/HTM.

Particularly, the charge transporting abilities of HTMs are crucial to fabricate high-performance PSCs and the conductivity and hole mobility of **ZnTPPc** were first studied. The electrical conductivitywas determined by measuring the current-voltage (I-V) curve of the device with simple structure (FTO/HTM/Ag) following the equation of $\sigma = IA^{-1}V^{-1}d$, where A is the active area of the device, *d* is the thickness of HTM.

The calculated conductivity of ZnTPPc was found to be 2.9 × 10-6 S cm-1, and for pristine Spiro-OMeTAD was $6.9 \times 10-7$ S cm-1, showing the similar values reported elsewhere (10^{-7} - 10^{-8} S cm⁻¹).^{10,49} The conductivity value of ZnTPPc is notably one magnitude higher than the value of pristine Spiro-OMeTAD. Besides, the hole mobility of the **ZnTPPc** and pristine Spiro was evaluated by space charge limited current (SCLC) method using a hole-only device with the architecture of FTO/PEDOT:PSS/**HTM**/Ag. The current density-voltage (*J-V*)



Fig.3 Top-view SEM images of (a) bare perovskite and (b) perovskite/**ZnTPPc** film. AFM height images of the (c) bare perovskite and (d) perovskite/**ZnTPPc** film. Corresponding 3D AFM images of the (e) bare perovskite and (f) perovskite/**ZnTPPc** film.

curve was tested under the dark and ambient condition and the hole mobility was calculated using the Mott-Gurney law $(J=9\epsilon_0\mu V_{app}^2/8d^3)$. The obtained hole mobility of **ZnTPPc** was 4.1×10^{-5} cm² V⁻¹ s⁻¹, which is higher than that of pristine Spiro-OMeTAD (1.7×10^{-5} cm² V⁻¹ s⁻¹).^{50,51} The relative higher conductivity and mobility of ZnTPPc resulted in improvement of fill factor and charge transporting ability can improve the device performance.

The film-forming ability of novel HTM was investigated by Scanning Electron Microscopy (SEM) and Atomic Force Microscopy (AFM). The Fig. 3a&3b showed the top-view SEM of bare perovskite and perovskite covered with ZnTPPc (named by perovskite/ZnTPPc), respectively. Compared to bare perovskite, the surface morphology of perovskite/ZnTPPc film shows fullcoverage film without any voids or defects. As shown in Fig. 3c&3d, the AFM topographical images of bare perovskite film displayed a root mean square (RMS) roughness of 29.1 nm. The surface of perovskite/ZnTPPc presented smooths with decreased RMS of 19.6 nm. The uniform, smooth HTM film can extract photo-generated holes effectively and avoid interfacial recombination loss, and improve the device performance. In all, the **ZnTPPc** armed with such excellent properties such as matched energy level with perovskite and relatively high conductivity/mobility, good film-forming ability demonstrates great potential towards fabricating efficient PSCs.

Photovoltaic performance of PSCs with ZnTPPc as HTM

To validate the potential of **ZnTPPc** as an efficient HTM in PSCs, we fabricated devices with an architect of FTO/*b*&*mp*-TiO₂/perovskite/**ZnTPPc**/Au (*b*&*mp*-TiO₂ presents blocking and mesoporous double TiO₂, **Fig 4a**) and for comparative purpose, pristine and doped Spiro-OMeTAD were used as reference HTM. Fig 4b shows a representative cross-sectional SEM image of PSC

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Fig. 4 (a) Device structure and (b) cross-sectional SEM images of the PSCs with ZnTPPc. (c) Schematic of the energy level of the PSCs with ZnTPPc. (d) J-V curves characterized under simulated AM 1.5G illumination for the devices with different HTMs. (e) EQE and Integrated J_{sc} of the champion device based on different HTMs. (f) Absorbance spectra of different thin films. (g) Steady state photoluminescence spectra of perovskite film with different HTMs. (h) Steady-state power output at the maximum power point for the champion device with ZnTPPc as an HTM. (i) Histograms of PCE performance parameters of PSCs with ZnTPPc as an HTM. The data was analyzed from 20 cells. Spiro-OMeTAD is referred to as Spiro.

device with ZnTPPc as an HTM, where the mixed perovskite atop of mp-TiO₂ was prepared by a two-step deposition method and the thickness was controlled upto ~ 450 nm. 17,18,25 A thin layer of ZnTPPc covered on perovskite film allows around 60 nm thick film. The energy level diagram (Fig. 3c) of ZnTPPc based device shows a well matched HOMO-LUMO energy level with respect the perovskite and thus exhibit the stronger possibility of transporting the holes efficiently. he J-V curves of the champion device with different HTMs were measured under reverse scan and corresponding photovoltaic parameters are shown in Fig. 4d and Table 1. The PSC with ZnTPPc yielded an overall PCE of 14.50%, with an open-circuit voltage ($V_{\rm oc}$) of 994.3 mV, a short circuit current density (J_{sc}) of 21.0 mA cm⁻², and a fill factor (FF) of 69.42%. A reference device with Spiro-OMeTAD conventional doped with lithium bis(trifluoromethanesulfonyl)imide (LiTFSI) and 4-tert-Butylpyridine (tBP) was fabricated with the same condition, and exhibited a PCE of 17.75% with a V_{oc} of 1098.8 mV, a J_{sc} of 21.63 mA cm⁻², and a FF of 73.44%, which was slightly higher than that of the device with pristine ZnTPPc. However, when using pristine Spiro-OMeTAD as a HTM, the device showed inferior PV parameters having PCE of 5.14%, with a $V_{\rm oc}$ of 993.9 mV, $J_{\rm sc}$ of 15.25 mA cm⁻², *FF* of 33.92%. Notably, low J_{sc} and FF was found due to the poor electrical properties of Spiro-OMeTAD in its pristine form. The series resistance (R_s) of different HTMs are shown in Table 1. The **ZnTPPc**-based device displayed the R_s of 58 Ω , which is comparable with the value of doped Spiro-OMeTAD device (44 Ω) and lower than the value of pristine Spiro-OMeTAD device (424 Ω). Subsequently, the relative low R_s of **ZnTPPc**-based device allowed us to achieve improved FF and subsequently PCE.^{52–54}

Fig. 4e presents the external quantum efficiency (EQE) spectra and the integrated current density (integrated J_{sc}). The integrated J_{sc} values of PSCs with **ZnTPPc**, pristine and doped Spiro-OMeTAD are 19.41, 19.06, and 20.86 mA cm⁻², respectively, close to the J_{sc} value attained from *J-V* curves under the standard solar AM 1.5G. The lower J_{sc} value of the **ZnTPPc**-based device obtained from EQE spectra compared with doped Spiro-OMeTAD is in agreement with the value from the *J-V* curves. The device with **ZnTPPc** and Spiro-OMeTAD own the same EQE value at wavelength ranging from 300 nm to 580 nm, while the device with Spiro-OMeTAD at wavelength ranging from 580 nm to 800 nm. Considering the strong absorbance of

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Fig. 5 Statistical box plots of the photovoltaic performance parameters of devices using **ZnTPPc** (a, b, c, d) vs different storage time. The data was analysed from 20 cells. (e) Normalized values of device performance parameters of ZnTPPc-based PSCs during aging. (f) Contact angle of perovskite film with different HTMs.

phthalocyanine at wavelength ranging from 580 nm to 800 nm (Fig. 1a&4f), one possible reason of decreased EQE and J_{sc} of **ZnTPPc**-based device is that unabsorbed long-wavelength light passing through the perovskite active layer was absorbed by ZnTPPc instead of being reflected by the electrode and reabsorbed by the perovskite layer, leading to the decrease of photocurrent and efficiency.

Photoluminescence (PL) characterization for perovskite with different HTMs on the quartz substrate was used to analyse the charge carrier separation and transport process.55–58 In order to see the hole extraction ability of different HTMs, steady state photoluminescence (PL) measurement was done using samples with the structure of quartz/perovskite/HTM.

Fig. 4g. shows the steady state PL spectra for pristine perovskite and with different HTM excited from the quartz side at 600 nm. The strong PL emission peak centred at 798 nm was observed for pristine perovskite while a decrease in PL intensity was noticed with all the HTM samples indicating the efficient hole extraction. Although, All HTMs can quench the PL of perovskite, however, doped Spiro-OMeTAD exhibit the strong PL quenching compared to undoped Spiro and ZnTPPc.

Interestingly, in case of **ZnTPPc**, blue shifted PL peak (from 798 to 787 nm at the Pero/ZnTPPC was observed, which might be ascribed to a decrease in the surface trap states⁵⁹ on the surface and grain boundaries of perovskite layer, since surface roughness and film morphology was improved after ZnTPPc deposition as shown in Figure 3b-d. The hysteresis effect of the device with ZnTPPc is observed, and the performance tested under reverse scanning (14.50%) is higher than that of forward scanning (11.34%) as shown in Fig S8 and Table S1. To evaluate the reliability of the device, the stabilized power output was measured as shown in Fig. 4h. The device with ZnTPPc showed 15.7 mA cm⁻² under the constant bias of near the maximum power point (0.78 V), and yielded stable PCE of 12.2%, in good agreement with the average PCE obtained from forward and reverse scan (12.92%). Besides, to check the reproducibility, 20 independent devices were statistically analysed, and the histograms of PCE (Fig. 4i) as well as $V_{\rm oc}$, $J_{\rm sc}$ and FF (Fig. S9) were summarized in Table 1. The average PCE

was 11.80±1.51%. Our results suggest good reproducibility of PSCs with **ZnTPPc** as an HTM possibly due to core structure, which has high tolerance power.

Table 1. Photovoltaic parameters	of the PSCs based on different HTMs.
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HTM	V _{oc} (mV)	J _{sc} (mA cm ⁻²)	FF (%)	PCE (%)	<i>R</i> _s (Ω)	$R_{\rm sh}$ (k Ω)
ZnTPPc	994.3	21.00	69.42	14.50	58	19.2
Pristine Spiro	993.9	15.25	33.92	5.14	424	1.7
Doped Spiro	1075.9	23.62	72.69	18.47	44	5.6
ZnTPPc (statistics)	1011.4±21	19.92±0.81	58.42±5.6	11.80±1.51		

Apart from the performance in terms of efficiency, the long-term stability of corresponding devices is another important parameter to further assess the potential of HTMs. These un-encapsulated devices were stored in a dry box with 40 - 50% relative humidity and room temperature condition. The ZnTPPc-based PSCs present average PCE of 12.75% after aging for 432 h, while the initial average values of the device were 12.31%, showing slight increases after aging (Fig. 5 and Table S2). Such phenomena typically originated from the optimization of interface contact by solvent drying with storage time. In contrast, the average PCE of the device with doped Spiro-OMeTAD dropped from 18.28% to 16.91% after aging 120 h under similar conditions (Fig. S10 and Table S2). More importantly, the average PCE of the ZnTPPc-based device remains 88% of initial efficiency after aging for over 3000 h (Fig. 5e and Table S3). This point towards ZnTPPc based PSCs superior stability. The plausible reasons for improved stability are as follows: the perovskite/ZnTPPc show a higher water contact angle of 98° compared to that of Spiro-OMeTAD (76°) (Fig. 5f), the excellent hydrophobic nature of ZnTPPc can effectively block the water penetration into perovskite layers.

To conclude, through molecular engineering, we have designed a tetrasubstituted **ZnTPPc** with electron-rich thienyltriphenylamine conjugated aromatic substituents. We found that **ZnTPPc** possesses excellent electrical properties such as relative high conductivity and mobility compared to pristine Spiro-OMeTAD, suitable energetic level alignment and can supress the trap state on the surface of perovskite. The

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perovskite solar cells fabricated thereof employing **ZnTPPc** as a hole selective layer gave a highly competitive power conversion efficiency over 14%, without the use of any dopant and additives. More importantly, the **ZnTPPc** maintained the initial efficiency after the aging measurement.

Experimental

Materials

Chemicals were purchased from Sigma Aldrich unless otherwise specified, whereas Na_2CO_3 was acquired from Scharlab, *N*-bromosuccinimide and K_2CO_3 from Alfa Aesar, 4-methoxy-*N*-(4-methoxyphenyl)-*N*-(4-(4,4,5,5-tetramethyl-

1,3,2-dioxaborolan-2-yl)phenyl)aniline from Fluorochem, and TBAB from Fluka. All chemicals were employed without any further treatment or purification. 4-iodophthalonitrile was synthesized according to the processes described in the literature.⁶⁰

All reactions were carried out under a nitrogen atmosphere. The solvents for spectroscopic studies were of spectroscopic grade and used as received. Column chromatography was carried out silica gel 60 ACC (40-63 μ m). Thin layer chromatography was performed on TLC plates coated with SiO₂ (40-63 μ m) 60F254.

Synthesis of ZnTPPc

60 mg (0.12 mmol) of **2**, 10.7 mg (0.058 mmol) of $Zn(OAc)_2$ and a drop of DBN were dissolved in 200 µL of DMAE and heated to reflux under nitrogen atmosphere for 16 h. After cooling at room temperature, DMAE was removed by distillation with toluene. The residue was passed by column chromatography (DCM:MeOH/95:5), the green solid obtained washed with MeOH at reflux, and finally purified by preparative TLC (DCM:MeOH, 96:4) affording **ZnTPPc** (32 mg, 52 %) as a green powder. UV-vis: λ_{max} (DMF)/nm (log \mathcal{E}): 390 (5.01), 647 (4.57), 719 (5.17). HRMS (MALDI-TOF-MS): For C₁₂₈H₉₂N₁₂O₈S₄Zn (M)⁺ calc. 2116.533, found 2116.581.

Synthesis of phthalonitrile 2

200 mg (0.69 mmol) of **3**, 300 mg (0.69 mmol) of 4methoxy-N-(4-methoxyphenyl)-N-(4-(4,4,5,5-tetramethyl-

1,3,2-dioxaborolan-2-yl)phenyl)aniline, 63.4 mg (0.069 mmol) of Pd₂(dba)₃, 145.2 mg (0.55 mmol) of PPh₃ and 11.4 mg (0.035 mmol) of TBAB were dissolved in 16 mL of degassed toluene. A degassed 2M solution of K₂CO₃ was added and heated to 90 °C under nitrogen atmosphere for 24 hours. After cooling at room temperature, the crude was filtered and concentrated. Purification by column chromatography using hexane:ethyl acetate (7:3) afforded **2** (168 mg, 48%) as a red powder. ¹H NMR (CDCl₃): δ = 3.81 (s, 6H), 6.89 (m, 6H), 7.09 (m, 4H), 7.22 (d, *J*= 3.9, 1H), 7.42 (m, 3H), 7.75 (dd, *J*= 8.3, 0.4, 1H), 7.86 (dd, *J*= 8.3, 1.9, 1H), 7.96 (dd, *J*= 1.9, 0.4, 1H). ¹³C NMR (CDCl₃): δ = 55.5, 112.3, 114.8, 115.3, 115.6, 116.6, 119.7, 123.1, 124.6, 126.5, 127.0, 127.6, 128.5, 129.3, 133.9, 136.5, 139.5, 140.1, 148.6, 149.3, 156.4. UV-vis: λ_{max} (CHCl₃)/nm (log ϵ): 451 (4.39). HRMS

(MALDI-TOF-MS): For $C_{32}H_{23}N_3O_2S~(M)^+$ calc. 513.151 found 513.122.

Synthesis of phthalonitrile 3

500 mg (2.38 mmol) of **4** were dissolved in 12 mL of DCM and cooled to 0 °C. A solution of 634.8 mg (3.57 mmol) of *N*bromosuccinimide (NBS) dissolved in 12 ml of acetic acid was added dropwise for 30 minutes, and stayed at room temperature overnight. The reaction was carried in darkness. Then it was cooled to 0 °C, the solid obtained was filtered and washed with hexane (410 mg, 60 %). ¹H NMR (CDCl₃): δ = 7.15 (d, *J*= 4.0, 1H), 7.25 (d, *J*= 4.0, 1H), 7.80 (s, 1H), 7.80 (s, 1H), 7.90 (t, *J*= 1.2, 1H). ¹³C NMR (CDCl₃): δ = 112.5, 114.3, 114.6, 114.8, 115.7, 126.6, 128.5, 128.9, 131.1, 133.5, 137.6, 140.0.

Synthesis of phthalonitrile 4

1 g (3.94 mmol) of 4-iodophthalonitrile, 910 mg (4.33 mmol) of thiophene-2-boronic acid pinacol ester, 42 mg (0.19 mmol) of palladium(II) acetate and 206.5 mg (0.79 mmol) of triphenylphosphine were dissolved in 10 mL of distilled and degassed 1,4-dioxane. Then, 4 mL of a degassed 2M solution of Na₂CO₃ was added and heated to 95°C under nitrogen atmosphere for 6h. After cooling at room temperature, the crude was treated with NH₄Cl 2M, extracted with DCM, washed with distilled water, dried over NaSO₄, filtered and concentrated to afford a white solid. Purification by column chromatography using hexane:toluene (1:4) as solvent, afforded 4 (680 mg, 83 %) as a white powder. ¹H NMR (CDCl₃): δ = 7.18 (dd, J= 5.0, 3.8, 1H), 7.50 (m, 2H), 7.80 (d, J= 8.3, 1H), 7.91 (dd, J= 8.3, 1.9, 1H), 8.00 (d, J= 1.9, 1H). ¹³C NMR (CDCl₃): δ = 111.9, 114.4, 114.6, 115.4, 126.0, 127.9, 128.1, 128.7, 129.0, 133.3, 138.5, 138.6.

Measurements for materials

NMR spectra were measured with a Bruker AC 300. UV-vis were recorded with a Helios Gamma spectrophotometer. Fluorescence spectra were recorded with a Perkin Elmer LS 55 Luminescence spectrophotometer. High-resolution mass spectra were obtained from a Bruker Microflex LRF20 matrix assisted laser desorption/ionization time of flight (MALDI-TOF) using dithranol as matrix.

Cyclic voltammetry was measured in a conventional threeelectrode cell using а μ-AUTOLAB type Ш potentiostat/galvanostat at 298 K over benzonitrile and deaerated sample solutions containing 0.10 М tetrabutylammonium hexafluorophosphate (TBAPF₆) as supporting electrolyte. Platinum as working electrode, Ag/AgNO₃ as the reference electrode, and platinum as wire counter electrode were employed. Ferrocene/Ferrocenium was used as an internal standard for all measurements.

Device fabrication and characterization

The pre-cleaned FTO (NSG10) substrates were treated with UV-ozone machine for 60 min each time and were heated to 500 °C. A compact blocking layer of TiO_2 were deposited by

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spray pyrolysis using a 5% titanium (IV) diisopropoxide bis(acetylacetonate) solution diluted by anhydrous ethanol. The substrates were kept at 500 °C for 30 min after the spraying. Mesoporous TiO₂ films were obtained by spin-coating a mesoporous dispersion of TiO₂ nanoparticles (30 NRD from Dyesol) and heated at 500 °C for 30 min to produce the mesoporous structure. The substrates were transferred to an argon-filled glovebox for depositing perovskite films. The twostep deposition method was adopted to prepare perovskite with high quality. In short, 1.3M PbI₂ precursor solution dissolving in a mixed solvent (volume ratio of DMF/DMSO=9.5/0.5) was spin coating at 2,000 rpm for 20 s to prepare PbI2 layer. The mixed organic precursor solution containing formamidinium iodide: methylammonium bromide: methylammonium chloride= 60: 6: 6 in 1 mL isopropanol was dynamically added to the PbI₂ layer and was spin-coated at 2,000 rpm for 20 s. The as-prepared film was annealed at 150 °C for 15 min in the glovebox. The ZnTPPc film layer was deposited atop perovskite films at a spin rate of 4,000 rpm for 20 s with 10 mM (~ 21 mg/mL) solution with chlorobenzene as the solvent. The Spio-OMeTAD hole transporting layer was prepared by spin-coated the Spiro-OMeTAD solution prepared by dissolving 72.3 mg material in 1 mL chlorobenzene. Finally, a ~ 70 nm gold electrode was deposited on top of the hole-transporting layer by thermal evaporation. J-V curves were recorded with a Keithley 2400 source-measurement-unit under AM 1.5 G, 100 mW cm² illumination from a 450 W 3A solar simulator (ORIEL, 94023 A). This was calibrated using an NREL certified calibrated monocrystalline silicon solar cell. Testing parameters: active area defined by black masks: 0.09 cm², scan rate: 100 mV s⁻¹, pre-sweep delay: 10 s). Surface and cross-sectional SEM images were recorded by using a Hitachi S-4800. The EQE spectra was measured using a 150 W Xenon lamp (Newport) attached to IQE200B (Oriel) motorized 1/4m monochromator as the light source. The water contact angle was tested by contact angle goniometer (Ossila). Absorption spectra was collected by Cary 60. Atomic Force Microscopy (AFM) images were acquired with CSI Nano observer AFM.

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